

DS92LV090A 9 Channel Bus LVDS Transceiver

General Description

The DS92LV090A is one in a series of Bus LVDS transceivers designed specifically for the high speed, low power proprietary backplane or cable interfaces. The device operates from a single 3.3V power supply and includes nine differential line drivers and nine receivers. To minimize bus loading, the driver outputs and receiver inputs are internally connected. The separate I/O of the logic side allows for loop back support. The device also features a flow through pin out which allows easy PCB routing for short stubs between its pins and the connector.

The driver translates 3V TTL levels (single-ended) to differential Bus LVDS (BLVDS) output levels. This allows for high speed operation, while consuming minimal power with reduced EMI. In addition, the differential signaling provides common mode noise rejection of $\pm 1V$.

The receiver threshold is less than ± 100 mV over a $\pm 1V$ common mode range and translates the differential Bus LVDS to standard (TTL/CMOS) levels. (See Applications Information Section for more details.)

Features

- Bus LVDS Signaling
- 3.2 nanosecond propagation delay max
- Chip to Chip skew ±800ps
- Low power CMOS design
- High Signaling Rate Capability (above 100 Mbps)
- 0.1V to 2.3V Common Mode Range for V_{ID} = 200mV
- ±100 mV Receiver Sensitivity
- Supports open and terminated failsafe on port pins
- 3.3V operation
- Glitch free power up/down (Driver & Receiver disabled)
- Light Bus Loading (5 pF typical) per Bus LVDS load
- Designed for Double Termination Applications
 Delenced Output Impedance
- Balanced Output Impedance
- Product offered in 64 pin TQFP package
- High impedance Bus pins on power off (V_{CC} = 0V)
- Driver Channel to Channel skew (same device) 230ps typical
- Receiver Channel to Channel skew (same device) 370ps typical

Simplified Functional Diagram



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DS92LV090A

Connection Diagram



Top View Order Number DS92LV090ATVEH See NS Package Number VEH064DB

Pin Descriptions

Pin Name	Pin #	Input/Output	Descriptions		
DO+/RI+	27, 31, 35, 37, 41, 45,	I/O	True Bus LVDS Driver Outputs and Receiver Inputs.		
	47, 51, 55				
DO-/RI-	26, 30, 34, 36, 40, 44,	I/O	Complimentary Bus LVDS Driver Outputs and Receiver Inputs.		
	46, 50, 54				
D _{IN}	2, 6, 12, 18, 20, 22, 58,	I	TTL Driver Input.		
	60, 62				
RO	3, 7, 13, 19, 21, 23, 59,	0	TTL Receiver Output.		
	61, 63				
RE	17	I	Receiver Enable TTL Input (Active Low).		
DE	16	Ι	Driver Enable TTL Input (Active High).		
GND	4, 5, 9, 14, 25, 56	Power	Ground for digital circuitry (must connect to GND on PC board). These pins		
			connected internally.		
V _{cc}	10, 15, 24, 57, 64	Power	V _{CC} for digital circuitry (must connect to V _{CC} on PC board). These pins		
			connected internally.		
AGND	28, 33, 43, 49, 53	Power	Ground for analog circuitry (must connect to GND on PC board). These pins		
			connected internally.		
AV _{CC}	29, 32, 42, 48, 52	Power	Analog V_{CC} (must connect to V_{CC} on PC board). These pins connected		
			internally.		
NC	1, 8, 11, 38, 39	N/A	Leave open circuit, do not connect.		
	1, 0, 11, 30, 39	N/A			

Absolute Maximum Ratings (Notes 1, 2)

If Military/Aerospace specified devices are required, please contact the National Semiconductor Sales Office/ Distributors for availability and specifications.

Supply Voltage (V _{CC})	4.0V
Enable Input Voltage	
(DE, RE)	–0.3V to (V _{CC} +0.3V)
Driver Input Voltage (D _{IN})	–0.3V to (V _{CC} +0.3V)
Receiver Output Voltage	
(R _{OUT})	–0.3V to (V _{CC} +0.3V)
Bus Pin Voltage (DO/RI±)	-0.3V to +3.9V
ESD (HBM 1.5 kΩ, 100 pF)	>4.5 kV
Driver Short Circuit Duration	momentary
Receiver Short Circuit Duration	momentary
Maximum Package Power Dissipatio	n at 25°C
TQFP	1.74 W
Derate TQFP Package	13.9 mW/°C
θ _{ja}	71.7°C/W

 $\begin{array}{ll} \theta_{jc} & 10.9^\circ C/W \\ \mbox{Junction Temperature} & +150^\circ C \\ \mbox{Storage Temperature Range} & -65^\circ C \ to \ +150^\circ C \\ \mbox{Lead Temperature} \\ \mbox{(Soldering, 4 sec.)} & 260^\circ C \\ \end{array}$

Recommended Operating Conditions

	Min	Мах	Units
Supply Voltage (V _{CC})	3.0	3.6	V
Receiver Input Voltage	0.0	2.4	V
Operating Free Air Temperature	-40	+85	°C
Maximum Input Edge Rate			
(Note 6)(20% to 80%)			Δt/ΔV
Data		1.0	ns/V
Control		3.0	ns/V

DC Electrical Characteristics

Over recommended operating supply voltage and temperature ranges unless otherwise specified (Notes 2, 3)

Symbol	Parameter	Condit	ions	Pin	Min	Тур	Max	Units
V _{OD}	Output Differential Voltage	R_{L} = 27 Ω , Figure 1		DO+/RI+,	240	300	460	mV
ΔV_{OD}	V _{OD} Magnitude Change			DO-/RI-			27	mV
V _{OS}	Offset Voltage				1.1	1.3	1.5	V
ΔV _{OS}	Offset Magnitude Change					5	10	mV
V _{OH}	Driver Output High Voltage	R _L = 27Ω				1.4	1.65	V
V _{OL}	Driver Output Low Voltage	R _L = 27Ω			0.95	1.1		V
I _{OSD}	Output Short Circuit Current (Note 10)	$V_{OD} = 0V, DE = V_{CC},$ shorted together	Driver outputs			1361	l65l	mA
V _{OH}	Voltage Output High (Note	V _{ID} = +300 mV	I _{OH} = -400 μA	R _{OUT}	V _{CC} -0.2			V
	11)	Inputs Open			V _{CC} -0.2			V
		Inputs Terminated, $R_L = 27\Omega$			V _{CC} -0.2			V
V _{OL}	Voltage Output Low	$I_{OL} = 2.0 \text{ mA}, V_{ID} = -2.0 \text{ mA}$	300 mV			0.05	0.075	V
I _{OD}	Receiver Output Dynamic	$V_{ID} = 300 \text{mV}, V_{OUT} =$	V _{CC} -1.0V		-110	1751		mA
	Current (Note 10)	$V_{ID} = -300 \text{mV}, V_{OUT}$	= 1.0V			1751	110	mA
V_{TH}	Input Threshold High	DE = 0V, V _{CM} = 1.5V		DO+/RI+,			+100	mV
V _{TL}	Input Threshold Low			DO-/RI-	-100			mV
V_{CMR}	Receiver Common Mode Range				IV _{ID} I/2		2.4 – I V _{ID} I/2	v
I _{IN}	Input Current	$DE = 0V, \overline{RE} = 2.4V,$ $V_{IN} = +2.4V \text{ or } 0V$			-20	±1	+20	μA
		$V_{\rm CC} = 0V, V_{\rm IN} = +2.4$	V or 0V		-20	±1	+20	μA
V _{IH}	Minimum Input High Voltage			D _{IN} , DE, RE	2.0		V _{CC}	V
V _{IL}	Maximum Input Low Voltage				GND		0.8	V
I _{IH}	Input High Current	$V_{IN} = V_{CC} \text{ or } 2.4 V$			-20	±10	+20	μA
I _{IL}	Input Low Current	V _{IN} = GND or 0.4V			-20	±10	+20	μA
V _{CL}	Input Diode Clamp Voltage	$I_{CLAMP} = -18 \text{ mA}$			-1.5	-0.8		V

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Symbol	Parameter	Conditions	Pin	Min	Тур	Max	Units
I _{CCD}	Power Supply Current Drivers Enabled, Receivers Disabled	No Load, DE = \overline{RE} = V _{CC} , DIN = V _{CC} or GND	V _{cc}		55	80	mA
I _{CCR}	Power Supply Current Drivers Disabled, Receivers Enabled	$DE = \overline{RE} = 0V, V_{ID} = \pm 300 mV$			73	80	mA
I _{CCZ}	Power Supply Current, Drivers and Receivers TRI- STATE [®]	$DE = 0V; \overline{RE} = V_{CC},$ DIN = V _{CC} or GND			35	80	mA
I _{CC}	Power Supply Current, Drivers and Receivers Enabled	$DE = V_{CC}; \overline{RE} = 0V,$ DIN = V _{CC} or GND, R _L = 27\Omega			170	210	mA
I _{OFF}	Power Off Leakage Current	$V_{CC} = 0V \text{ or OPEN},$ $D_{IN}, DE, \overline{RE} = 0V \text{ or OPEN},$ $V_{APPLIED} = 3.6V (Port Pins)$	DO+/RI+, DO-/RI-	-20		+20	μA
C _{OUTPUT}	Capacitance @ Bus Pins		DO+/RI+, DO-/RI-		5		pF
COUTPUT	Capacitance @ R _{OUT}		R _{OUT}		7		pF

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AC Electrical Characteristics Over recommended operating supply voltage and temperature ranges unless otherwise specified (Note 6) Conditions Units Symbol Parameter Min Тур Max DIFFERENTIAL DRIVER TIMING REQUIREMENTS Differential Prop. Delay High to Low (Note 8) 0.6 $R_1 = 27\Omega$ 1.4 2.2 t_{PHLD} ns Differential Prop. Delay Low to High (Note 8) Figures 2, 3, 0.6 1.4 2.2 ns t_{PLHD} $C_1 = 10 \, pF$ Differential Skew It_{PHLD}-t_{PLHD}I (Note 9) 80 t_{SKD1} ps Chip to Chip Skew (Note 12) 1.6 t_{SKD2} ns Channel to Channel Skew (Note 13) 0.45 0.25 t_{SKD3} ns Transition Time Low to High 0.6 1.2 t_{TLH} ns Transition Time High to Low t_{THL} 0.5 1.2 ns Disable Time High to Z 8 $R_1 = 27\Omega$, З t_{PHZ} ns Disable Time Low to Z Figures 4, 5, 3 8 t_{PLZ} ns $C_{1} = 10 \, \text{pF}$ t_{PZH} Enable Time Z to High 3 8 ns Enable Time Z to Low 3 8 ns t_{PZL} DIFFERENTIAL RECEIVER TIMING REQUIREMENTS Differential Prop. Delay High to Low (Note 8) Figures 6, 7, 1.6 2.4 3.2 t_{PHLD} ns C_L = 35 pF Differential Prop Delay Low to High (Note 8) 1.6 2.4 3.2 t_{PLHD} ns Differential Skew It_{PHLD}-t_{PLHD}I (Note 9) 80 ps t_{SDK1} Chip to Chip Skew (Note 12) 1.6 t_{SDK2} ns Channel to Channel Skew (Note 13) 0.35 0.60 ns t_{SDK3} Transition Time Low to High 2.5 1.5 t_{TLH} ns Transition Time High to Low 1.5 2.5 t_{THL} ns Disable Time High to Z 4.5 10 t_{PHZ} $R_{I} = 500\Omega$, ns Disable Time Low to Z Figures 8, 9, 8 t_{PLZ} 3.5 ns $C_1 = 35 \, pF$ Enable Time Z to High 8 3.5 t_{PZH} ns Enable Time Z to Low 3.5 8 ns t_{PZL}

Note 1: "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed. They are not meant to imply that the devices should be operated at these limits. The table of "Electrical Characteristics" provides conditions for actual device operation.

Note 2: All currents into device pins are positive; all currents out of device pins are negative. All voltages are referenced to ground unless otherwise specified except V_{OD} , ΔV_{OD} and V_{ID} .

Note 3: All typicals are given for V_{CC} = +3.3V and T_A = +25°C, unless otherwise stated.

Note 4: ESD Rating: HBM (1.5 k Ω , 100 pF) > 4.5 kV EIAJ (0 Ω , 200 pF) > 300V.

Note 5: CL includes probe and fixture capacitance.

Note 6: Generator waveforms for all tests unless otherwise specified: f = 25 MHz, $Z_O = 50\Omega$, t_r , $t_r = <1.0 \text{ ns}$ (0%–100%). To ensure fastest propagation delay and minimum skew, data input edge rates should be equal to or faster than 1ns/V; control signals equal to or faster than 3ns/V. In general, the faster the input edge rate, the better the AC performance.

Note 7: The DS92LV090A functions within datasheet specification when a resistive load is applied to the driver outputs.

Note 8: Propagation delays are guaranteed by design and characterization.

Note 9: t_{SKD1} $t_{PHLD} - t_{PLHD}$ is the worse case skew between any channel and any device over recommended operation conditions.

Note 10: Only one output at a time should be shorted, do not exceed maximum package power dissipation capacity.

Note 11: V_{OH} failsafe terminated test performed with 27Ω connected between RI+ and RI- inputs. No external voltage is applied.

Note 12: Chip to Chip skew is the difference in differential propagation delay between any channels of any devices, either edge.

Note 13: Channel to Channel skew is the difference in driver output or receiver output propagation delay between any channels within a device, either edge.

Applications Information

General application guidelines and hints may be found in the following application notes: AN-808, AN-903, AN-971, AN-977, and AN-1108.

There are a few common practices which should be implied when designing PCB for Bus LVDS signaling. Recommended practices are:

- Use at least 4 PCB board layer (Bus LVDS signals, ground, power and TTL signals).
- Keep drivers and receivers as close to the (Bus LVDS port side) connector as possible.
- Bypass each Bus LVDS device and also use distributed bulk capacitance between power planes. Surface mount capacitors placed close to power and ground pins work best. Two or three high frequency, multi-layer ceramic (MLC) surface mount (0.1 μ F, 0.01 μ F, 0.001 μ F) in parallel should be used between each V_{CC} and ground. The capacitors should be as close as possible to the V_{CC} pin. Multiple vias should be used to connect V_{CC} and Ground planes to the pads of the by-pass capacitors. In addition, randomly distributed by-pass capacitors should be used.
- Use the termination resistor which best matches the differential impedance of your transmission line.
- Leave unused Bus LVDS receiver inputs open (floating). Limit traces on unused inputs to <0.5 inches.
- Isolate TTL signals from Bus LVDS signals

MEDIA (CONNECTOR or BACKPLANE) SELECTION:

 Use controlled impedance media. The backplane and connectors should have a matched differential impedance.

Test Circuits and Timing Waveforms

TABLE 1. Functional Table

MODE SELECTED	DE	RE
DRIVER MODE	Н	Н
RECEIVER MODE	L	L
TRI-STATE MODE	L	Н
LOOP BACK MODE	Н	L

TABLE 2. Transmitter Mode

	INPUTS	OUTPUTS		
DE	D _{IN}	DO+	DO-	
Н	L	L	Н	
Н	Н	Н	L	
Н	0.8V< D _{IN} <2.0V	Х	Х	
L	Х	Z	Z	

TABLE 3. Receiver Mode

	OUTPUT	
RE	(RI+) – (RI–)	
L	L (< –100 mV)	L
L	H (> +100 mV)	Н
L	–100 mV < V _{ID} < +100 mV	Х
Н	Х	Z

X = High or Low logic state

L = Low state Z = High impedance state

Z = High impedaH = High state



FIGURE 1. Differential Driver DC Test Circuit



FIGURE 2. Differential Driver Propagation Delay and Transition Time Test Circuit



FIGURE 3. Differential Driver Propagation Delay and Transition Time Waveforms



FIGURE 4. Driver TRI-STATE Delay Test Circuit







FIGURE 6. Receiver Propagation Delay and Transition Time Test Circuit







FIGURE 8. Receiver TRI-STATE Delay Test Circuit



FIGURE 9. Receiver TRI-STATE Delay Waveforms



Physical Dimensions inches (millimeters) unless otherwise noted



64-Lead Molded TQFP Package Order Number DS92LV090ATVEH NS Package Number VEH064DB

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Notes

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Ethernet	www.national.com/ethernet	Packaging	www.national.com/packaging			
Interface	www.national.com/interface	Quality and Reliability	www.national.com/quality			
LVDS	www.national.com/lvds	Reference Designs	www.national.com/refdesigns			
Power Management	www.national.com/power	Feedback	www.national.com/feedback			
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LDOs	www.national.com/ldo					
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